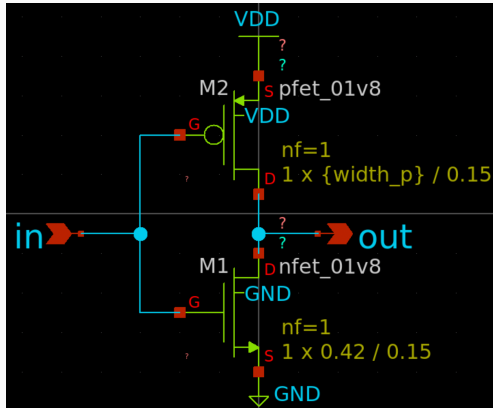


EE5311: Digital IC Design

Tutorial 3

Experiment 1a

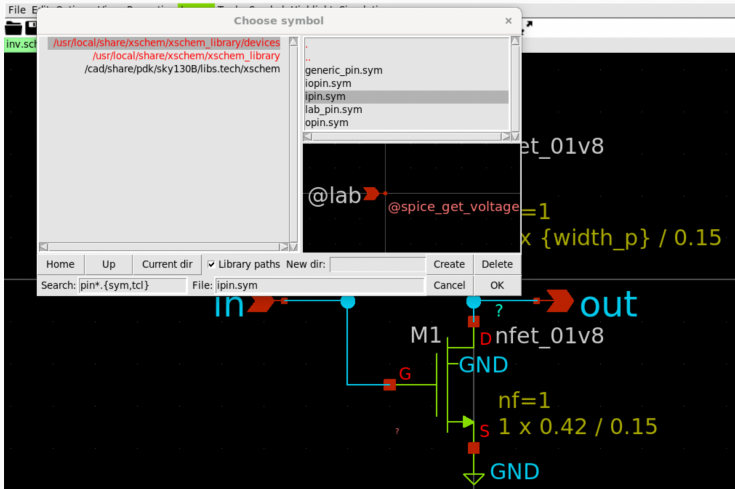
1a) Obtain the delay for $W_p = 0.42 \mu\text{m}$, $0.84 \mu\text{m}$, $1.26 \mu\text{m}$
Create inverter schematic as below:



Experiment 1a

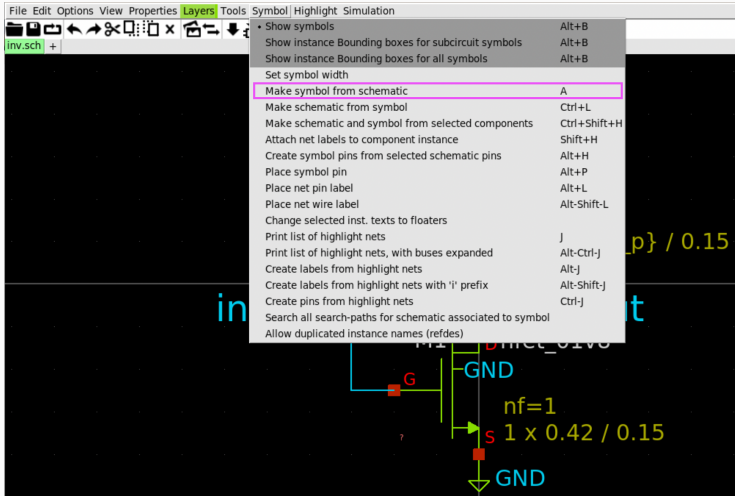
Input and output pins are in

xschem_library ► devices ► ipin/opin



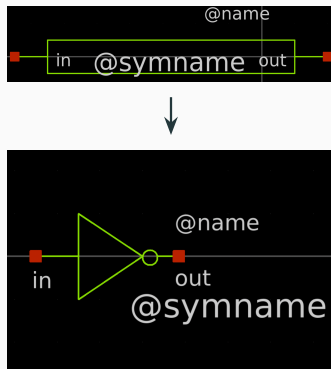
Experiment 1a

Make symbol for inverter using:



Experiment 1

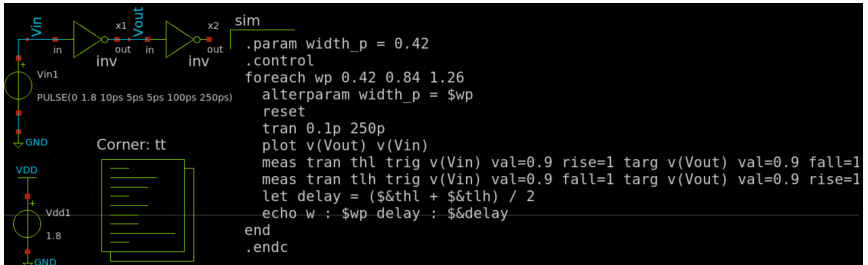
Edit the default symbol to that of an inverter:



- Delete the unnecessary lines in the symbol editor by selecting them using mouse and pressing `delete` key
- Use the shortcut key `l` to draw lines in the symbol editor
- To create the circle, use the circle shortcut key on the menu bar

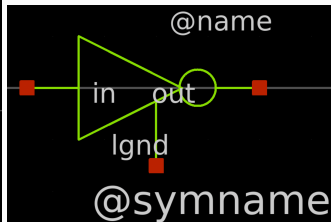
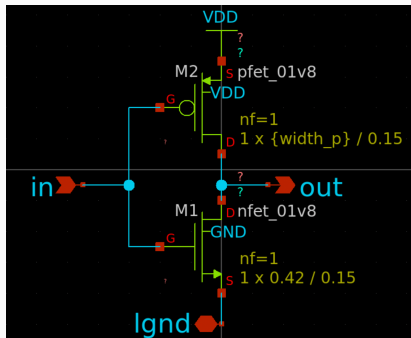
Experiment 1a

Sweep the pMOS widths and obtain the delays:



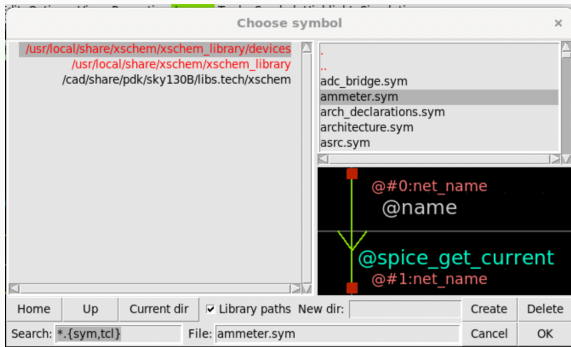
Experiment 1b, c

- Experiment 1c requires measurement of current through either the pMOS or nMOS to calculate the energy
- To attach an ammeter to the source pin of nMOS, create a new nMOS schematic and symbol **without** the gnd connection as below:

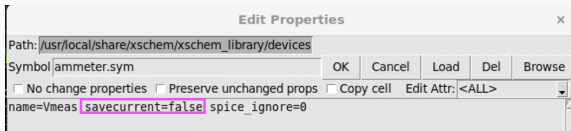


Experiment 1b, c

Insert an ammeter using: xschem_library ► devices ► ammeter



Ensure you mark the `savecurrent` option of the ammeter instance as `false`.



Experiment 1b, c

Find the delay and energy-delay product as a function of V_{DD} using:

